Bulletin PD-20406 rev. A 05/05

International
IOR Rectifier

30BQ015PbF

SCHOTTKY RECTIFIER

3 Amp

$I_{F(AV)}$ = 3.0Amp
V_R = 15V

Major Ratings and Characteristics

Characteristics	Value	Units
$I_{F(AV)}$ Rectangular waveform	3.0	A
V_{RRM}	15	V
I_{FSM} @t_p= 5 µs sine	650	A
V_F @1.0Apk, T_J = 75°C	0.30	V
T_J range	- 55 to 125	°C

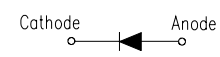
Description/ Features

The 30BQ015PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. The proprietary barrier technology allows for reliable operation up to 125°C junction temperature. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- 125°C T_J operation (V_R < 5V)
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Lead-Free ("PbF" suffix)

Case Styles

30BQ015PbF



SMC

Voltage Ratings

	Part number	30BQ015PbF
V_R	Max. DC Reverse Voltage (V)	15
V_{RWM}	Max. Working Peak Reverse Voltage (V)	25

Absolute Maximum Ratings

	Parameters	30BQ	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current	3.0	A	50% duty cycle @ T_L = 83 °C, rectangular wave form	
		4.0		50% duty cycle @ T_L = 78 °C, rectangular wave form	
I_{FSM}	Max. Peak One Cycle Non-Repetitive	650	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied
	Surge Current	75		10ms Sine or 6ms Rect. pulse	
E_{AS}	Non Repetitive Avalanche Energy	1.5	mJ	T_J = 25 °C, I_{AS} = 0.5A, L = 12mH	
I_{AR}	Repetitive Avalanche Current	0.5	A	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. Va = 1.5 x Vr typical	

Electrical Specifications

	Parameters	30BQ	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop (1)	0.35	V	@ 3A	T_J = 25 °C
		0.40	V	@ 6A	
		0.30	V	@ 3A	T_J = 75 °C
		0.35	V	@ 6A	
I_{RM}	Max. Reverse Leakage Current (1)	4	mA	T_J = 25 °C	V_R = rated V_R
		50	mA	T_J = 100 °C	
C_T	Max. Junction Capacitance	1120	pF	V_R = 5V_{DC} (test signal range 100KHz to 1Mhz) 25°C	
L_S	Typical Series Inductance	3.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V_R)	

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	30BQ	Units	Conditions
T_J	Max. Junction Temperature Range (*)	-55 to 125	°C	
T_{stg}	Max. Storage Temperature Range	-55 to 150	°C	
R_{thJL}	Max. Thermal Resistance Junction to Lead (**)	12	°C/W	DC operation
R_{thJA}	Max. Thermal Resistance Junction to Ambient	46	°C/W	DC operation
wt	Approximate Weight	0.24 (0.008)	g (oz.)	
	Case Style	SMC		Similar to DO-214AB
	Device Marking	IR3C		

(*) $\frac{dPtot}{dTj} < \frac{1}{Rth(j\text{-}a)}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

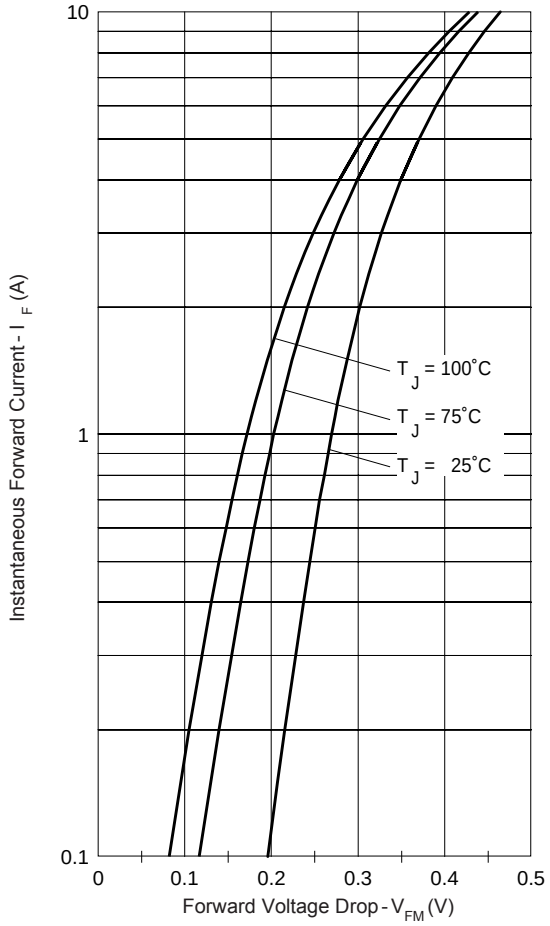


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

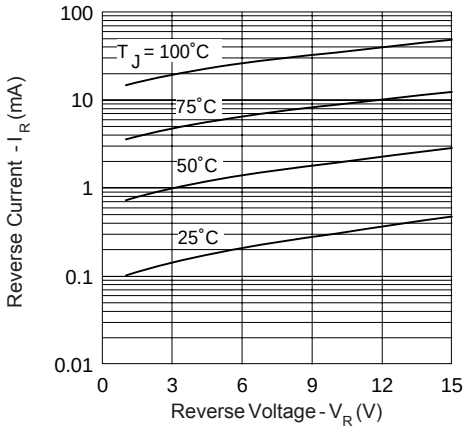


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

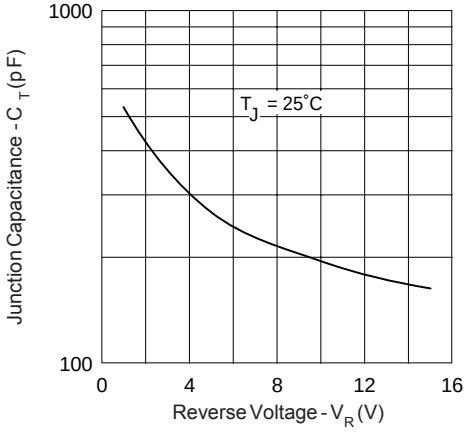


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

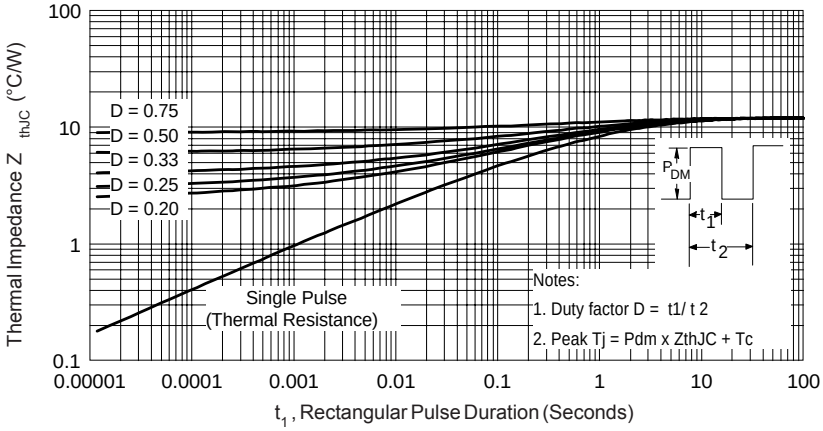


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (Per Leg)

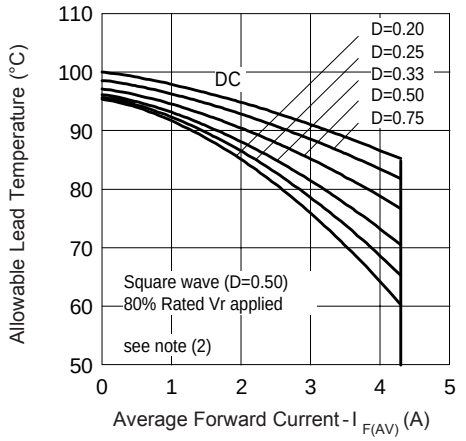


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

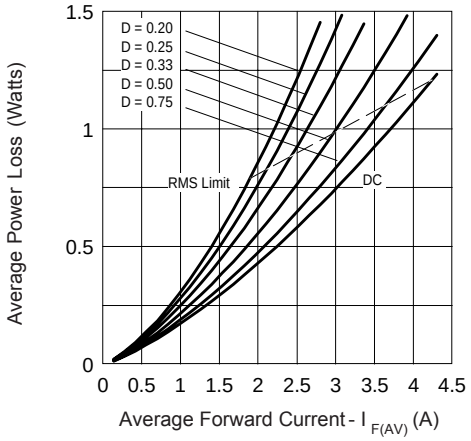


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

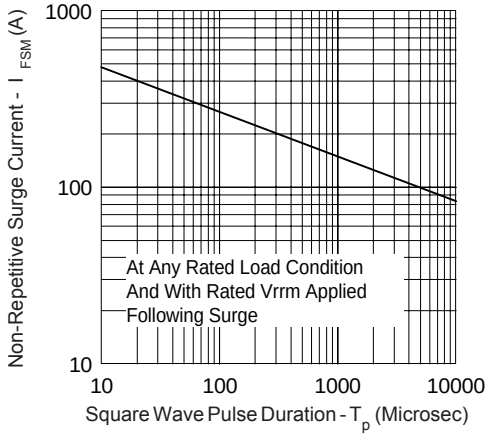
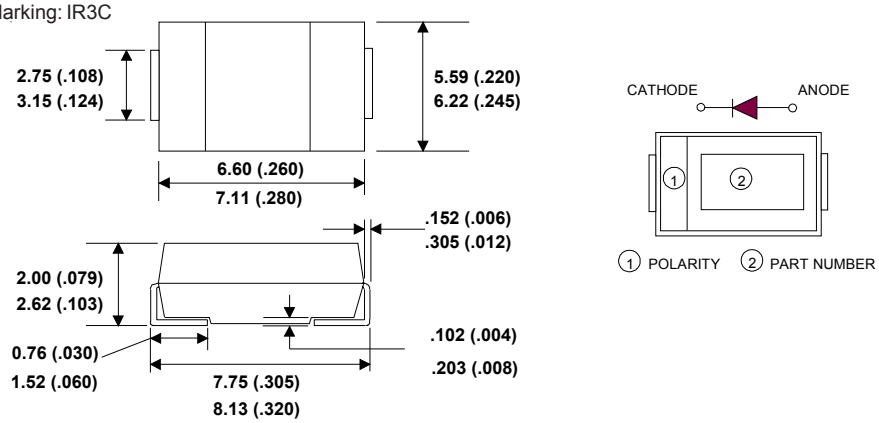


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1}$ = 80% rated V_R

Outline Table

Device Marking: IR3C



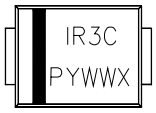
Outline SMC

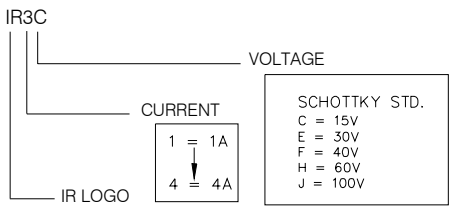
Dimensions in millimeters and (inches)

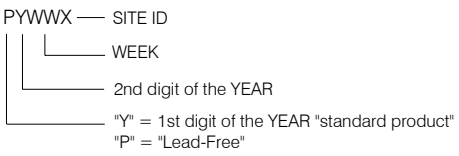
For recommended footprint and soldering techniques refer to application note #AN-994

Marking & Identification

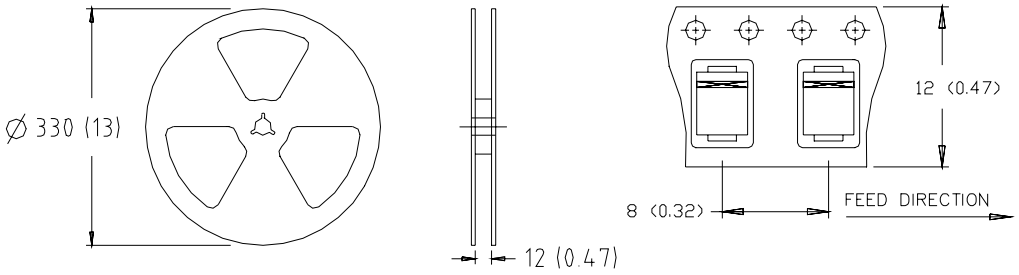
Each device has 2 rows for identification. The first row designates the device as manufactured by International Rectifier, indicated by the letters "IR", and the Part Number (indicates the current, the voltage rating and Schottky Generation). The second row indicates the year, the week of manufacturing and the Site ID.







Tape & Reel Information



Dimensions in millimetres and (inches)

Ordering Information Table

Device Code

30	B	Q	015	TR	PbF
1	2	3	4	5	6

1	-	Current Rating
2	-	B = Single Lead Diode
3	-	Q = Schottky Q Series
4	-	Voltage Rating (015 = 15V)
5	-	• none = Box (1000 pieces)
		• TR = Tape & Reel (3000 pieces)
6	-	• none = Standard Production
		• PbF = Lead-Free

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 05/05